



MOTOROLA

JFET Input Operational Amplifiers

These low-cost JFET input operational amplifiers combine two state-of-the-art linear technologies on a single monolithic integrated circuit. Each internally compensated operational amplifier has well matched high voltage JFET input devices for low input offset voltage. The BIFET technology provides wide bandwidths and fast slew rates with low input bias currents, input offset currents, and supply currents.

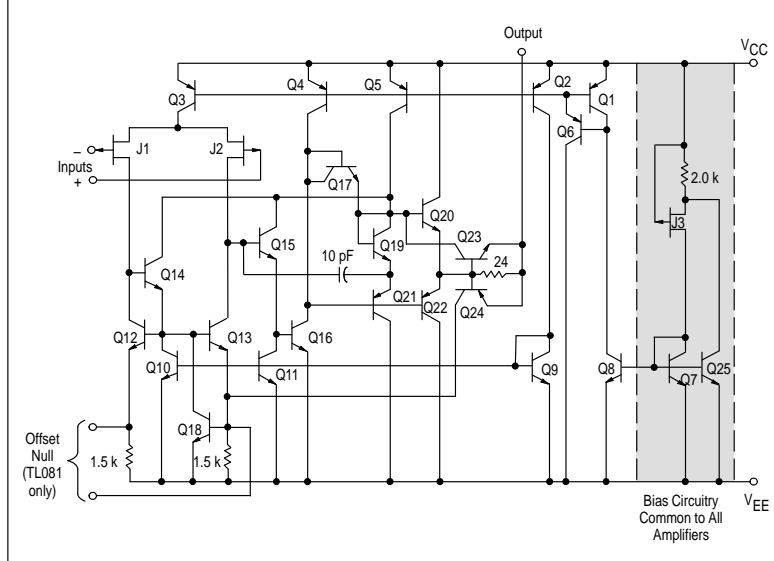
These devices are available in single, dual and quad operational amplifiers which are pin-compatible with the industry standard MC1741, MC1458, and the MC3403/LM324 bipolar products.

- Input Offset Voltage Options of 6.0 mV and 15 mV Max
- Low Input Bias Current: 30 pA
- Low Input Offset Current: 5.0 pA
- Wide Gain Bandwidth: 4.0 MHz
- High Slew Rate: 13 V/ μ s
- Low Supply Current: 1.4 mA per Amplifier
- High Input Impedance: $10^{12} \Omega$

ORDERING INFORMATION

Op Amp Function	Device	Operating Temperature Range	Package
Single	TL081CD	$T_A = 0^\circ$ to $+70^\circ\text{C}$	SO-8
	TL081ACP		Plastic DIP
Dual	TL082CD	$T_A = 0^\circ$ to $+70^\circ\text{C}$	SO-8
	TL082ACP		Plastic DIP
Quad	TL084CN, ACN	$T_A = 0^\circ$ to $+70^\circ\text{C}$	Plastic DIP

Representative Circuit Schematic (Each Amplifier)

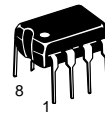


Order this document by TL081C/D

TL081C,AC TL082C,AC TL084C,AC

JFET INPUT OPERATIONAL AMPLIFIERS

SEMICONDUCTOR TECHNICAL DATA

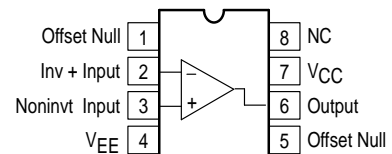


P SUFFIX
PLASTIC PACKAGE
CASE 626

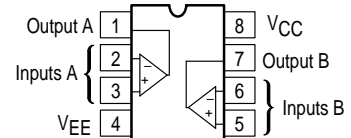


D SUFFIX
PLASTIC PACKAGE
CASE 751
(SO-8)

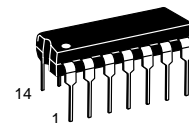
PIN CONNECTIONS



TL081 (Top View)

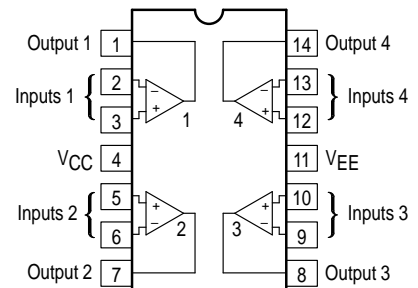


TL082 (Top View)



N SUFFIX
PLASTIC PACKAGE
CASE 646

PIN CONNECTIONS



TL084 (Top View)

TL081C,AC TL082C,AC TL084C,AC

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	V_{CC} V_{EE}	18 -18	V
Differential Input Voltage	V_{ID}	± 30	V
Input Voltage Range (Note 1)	V_{IDR}	± 15	V
Output Short Circuit Duration (Note 2)	t_{SC}	Continuous	
Power Dissipation Plastic Package (N, P) Derate above $T_A = +47^\circ\text{C}$	P_D $1/\theta_{JA}$	680 10	mW mW/ $^\circ\text{C}$
Operating Ambient Temperature Range	T_A	0 to +70	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$

- NOTES:** 1. The magnitude of the input voltage must not exceed the magnitude of the supply voltage or 15 V, whichever is less.
 2. The output may be shorted to ground or either supply. Temperature and/or supply voltages must be limited to ensure that power dissipation ratings are not exceeded.
 3. ESD data available upon request.

ELECTRICAL CHARACTERISTICS ($V_{CC} = 15\text{ V}$, $V_{EE} = -15\text{ V}$, $T_A = T_{low}$ to T_{high} [Note 1].)

Characteristics	Symbol	Min	Typ	Max	Unit
Input Offset Voltage ($R_S \leq 10\text{ k}$, $V_{CM} = 0$) TL081C, TL082C TL084C TL08_AC	V_{IO}	-	-	20 20 7.5	mV
Input Offset Current ($V_{CM} = 0$) (Note 2) TL08_C TL08_AC	I_{IO}	-	-	5.0 3.0	nA
Input Bias Current ($V_{CM} = 0$) (Note 2) TL08_C TL08_AC	I_{IB}	-	-	10 7.0	nA
Large-Signal Voltage Gain ($V_O = \pm 10\text{ V}$, $R_L \geq 2.0\text{ k}$) TL08_C TL08_AC	A_{VOL}	15 25	- -	- -	V/mV
Output Voltage Swing (Peak-to-Peak) ($R_L \geq 10\text{ k}$) ($R_L \geq 2.0\text{ k}$)	V_O	24 20	- -	- -	V

- NOTES:** 1. $T_{low} = 0^\circ\text{C}$ for TL081AC,C $T_{high} = 70^\circ\text{C}$ for TL081AC
 TL082AC,C TL082AC,C
 TL084AC,C TL084AC,C
 2. Input Bias currents of JFET input op amps approximately double for every 10°C rise in Junction Temperature as shown in Figure 3. To maintain junction temperature as close to ambient temperature as possible, pulse techniques must be used during testing.

Figure 1. Unity Gain Voltage Follower

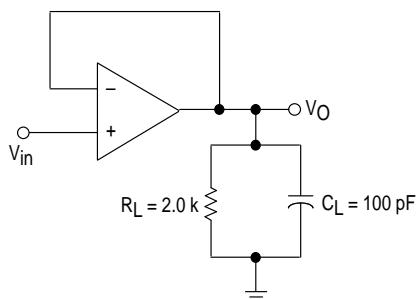
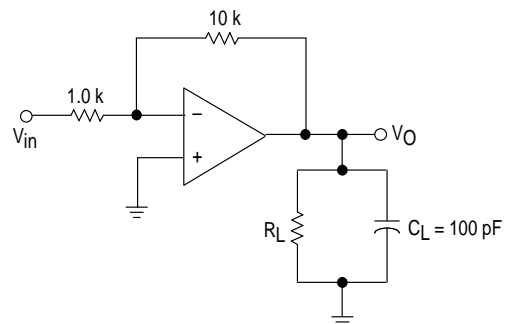


Figure 2. Inverting Gain of 10 Amplifier



TL081C,AC TL082C,AC TL084C,AC

ELECTRICAL CHARACTERISTICS ($V_{CC} = 15\text{ V}$, $V_{EE} = -15\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.)

Characteristics	Symbol	Min	Typ	Max	Unit
Input Offset Voltage ($R_S \leq 10\text{ k}$, $V_{CM} = 0$) TL081C, TL082C TL084C TL08_AC	V_{IO}	–	5.0 5.0 3.0	15 15 6.0	mV
Average Temperature Coefficient of Input Offset Voltage $R_S = 50\ \Omega$, $T_A = T_{low}$ to T_{high} (Note 1)	$\Delta V_{IO}/\Delta T$	–	10	–	$\mu\text{V}/^\circ\text{C}$
Input Offset Current ($V_{CM} = 0$) (Note 2) TL08_C TL08_AC	I_{IO}	–	5.0 5.0	200 100	pA
Input Bias Current ($V_{CM} = 0$) (Note 2) TL08_C TL08_AC	I_{IB}	–	30 30	400 200	pA
Input Resistance	r_i	–	10^{12}	–	Ω
Common Mode Input Voltage Range TL08_C TL08_AC	V_{ICR}	± 10 ± 11	15, –12 15, –12	– –	V
Large Signal Voltage Gain ($V_O = \pm 10\text{ V}$, $R_L \geq 2.0\text{ k}$) TL08_C TL08_AC	A_{VOL}	25 50	150 150	– –	V/mV
Output Voltage Swing (Peak-to-Peak) ($R_L = 10\text{ k}$)	V_O	24	28	–	V
Common Mode Rejection Ratio ($R_S \leq 10\text{ k}$) TL08_C TL08_AC	CMRR	70 80	100 100	– –	dB
Supply Voltage Rejection Ratio ($R_S \leq 10\text{ k}$) TL08_C TL08_AC	PSRR	70 80	100 100	– –	dB
Supply Current (Each Amplifier)	I_D	–	1.4	2.8	mA
Unity Gain Bandwidth	BW	–	4.0	–	MHz
Slew Rate (See Figure 1) $V_{in} = 10\text{ V}$, $R_L = 2.0\text{ k}$, $C_L = 100\text{ pF}$	SR	–	13	–	V/ μs
Rise Time (See Figure 1)	t_r	–	0.1	–	μs
Overshoot ($V_{in} = 20\text{ mV}$, $R_L = 2.0\text{ k}$, $C_L = 100\text{ pF}$)	OS	–	10	–	%
Equivalent Input Noise Voltage $R_S = 100\ \Omega$, $f = 1000\text{ Hz}$	e_n	–	25	–	$\text{nV}/\sqrt{\text{Hz}}$
Channel Separation $A_V = 100$	CS	–	120	–	dB

NOTES: 1. $T_{low} = 0^\circ\text{C}$ for TL081AC,C $T_{high} = 70^\circ\text{C}$ for TL081AC
 TL082AC,C TL082AC,C
 TL084AC,C TL084AC,C

2. Input Bias currents of JFET input op amps approximately double for every 10°C rise in Junction Temperature as shown in Figure 3. To maintain junction temperature as close to ambient temperature as possible, pulse techniques must be used during testing.

TL081C,AC TL082C,AC TL084C,AC

Figure 3. Input Bias Current versus Temperature

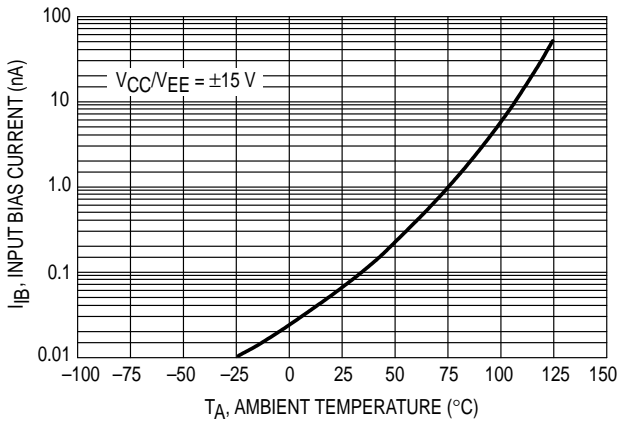


Figure 4. Output Voltage Swing versus Frequency

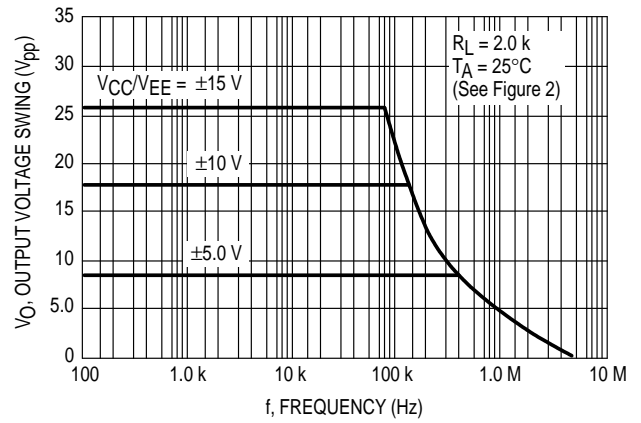


Figure 5. Output Voltage Swing versus Load Resistance

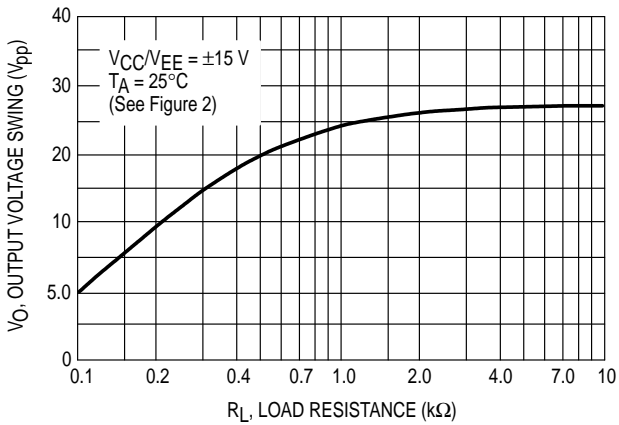


Figure 6. Output Voltage Swing versus Supply Voltage

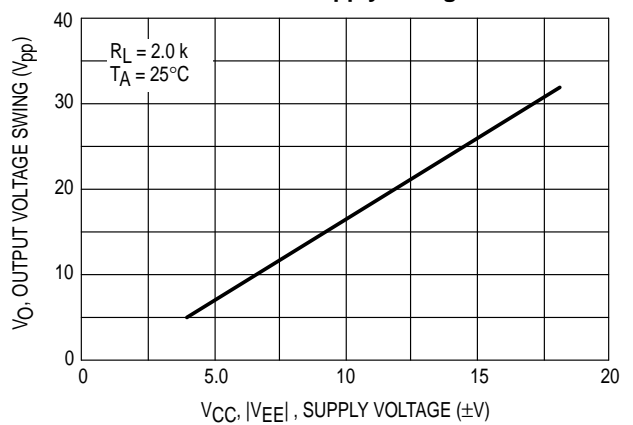


Figure 7. Output Voltage Swing versus Temperature

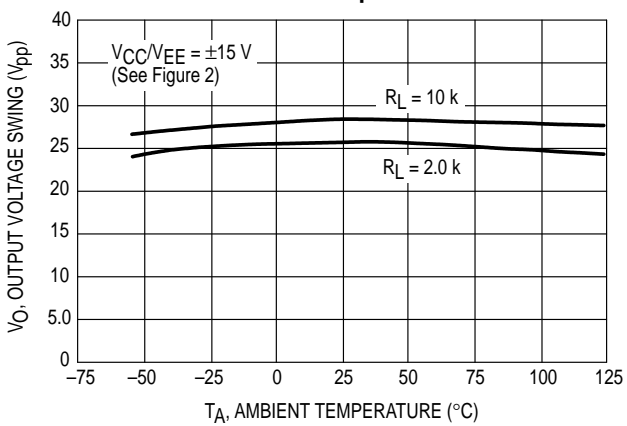
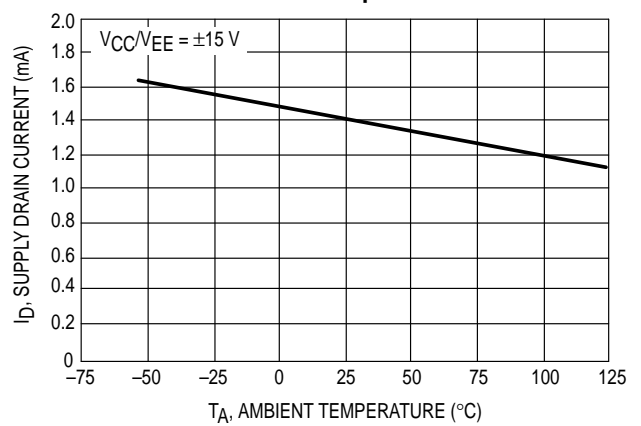


Figure 8. Supply Current per Amplifier versus Temperature



TL081C,AC TL082C,AC TL084C,AC

Figure 9. Large Signal Voltage Gain and Phase Shift versus Frequency

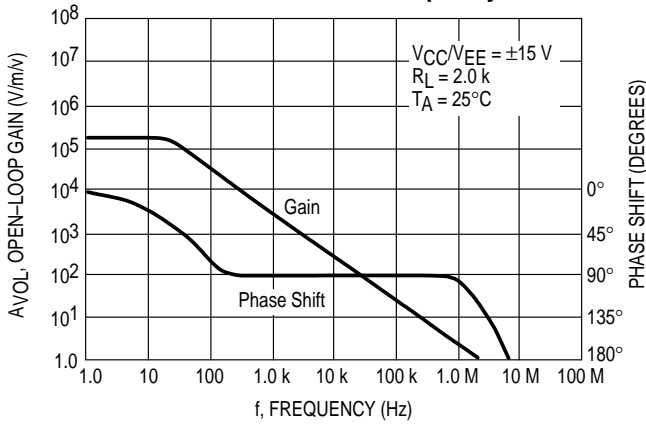


Figure 10. Large Signal Voltage Gain versus Temperature

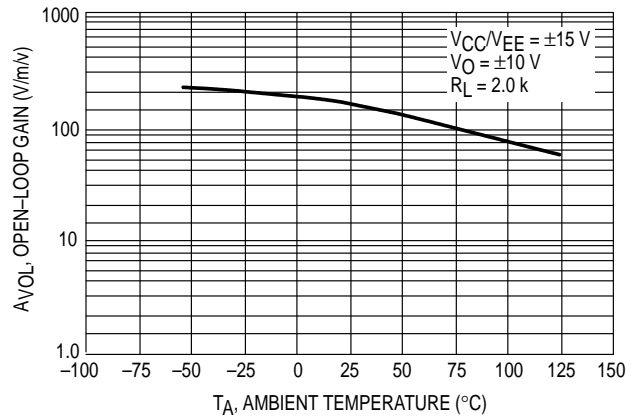


Figure 11. Normalized Slew Rate versus Temperature

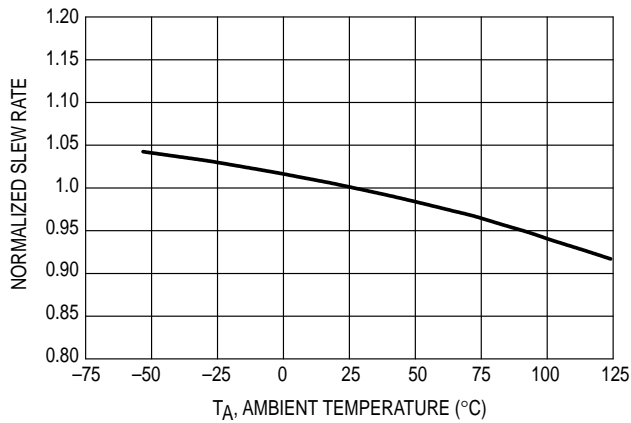


Figure 12. Equivalent Input Noise Voltage versus Frequency

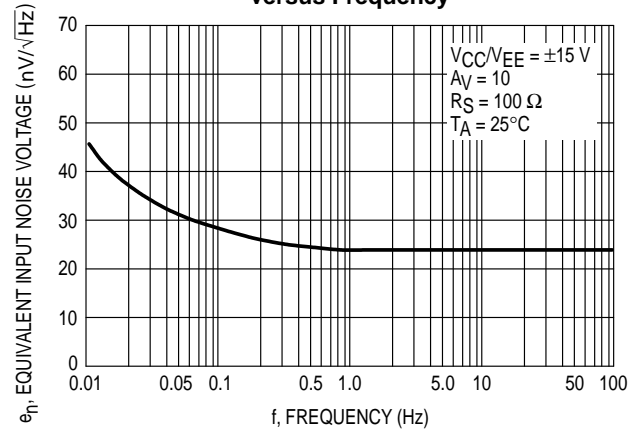
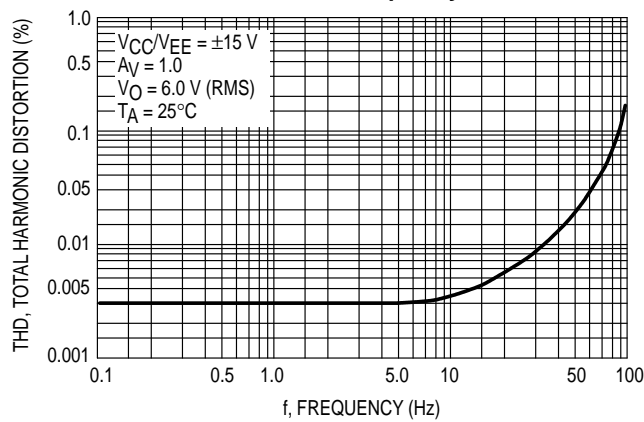


Figure 13. Total Harmonic Distortion versus Frequency



TL081C,AC TL082C,AC TL084C,AC

Figure 14. Positive Peak Detector

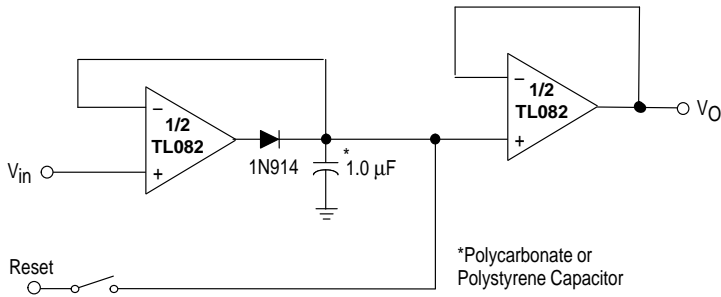


Figure 15. Voltage Controlled Current Source

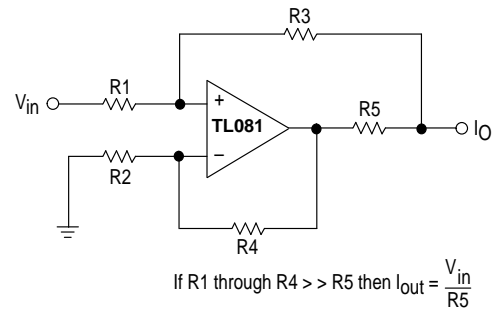
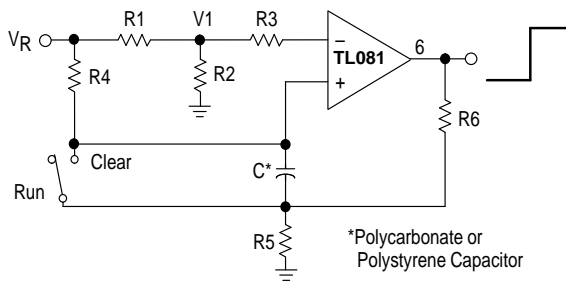


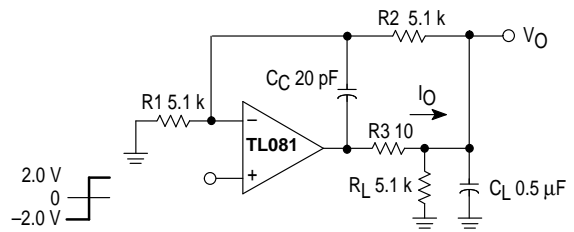
Figure 16. Long Interval RC Timer



Time (t) = $R_4 C \ln(V_R / V_R - V_I)$, $R_3 = R_4$, $R_5 = 0.1 R_6$
 If $R_1 = R_2$: $t = 0.693 R_4 C$

Design Example: 100 Second Timer
 $V_R = 10 \text{ V}$ $C = 1.0 \text{ mF}$ $R_3 = R_4 = 144 \text{ M}$
 $R_6 = 20 \text{ k}$ $R_5 = 2.0 \text{ k}$ $R_1 = R_2 = 1.0 \text{ k}$

Figure 17. Isolating Large Capacitive Loads



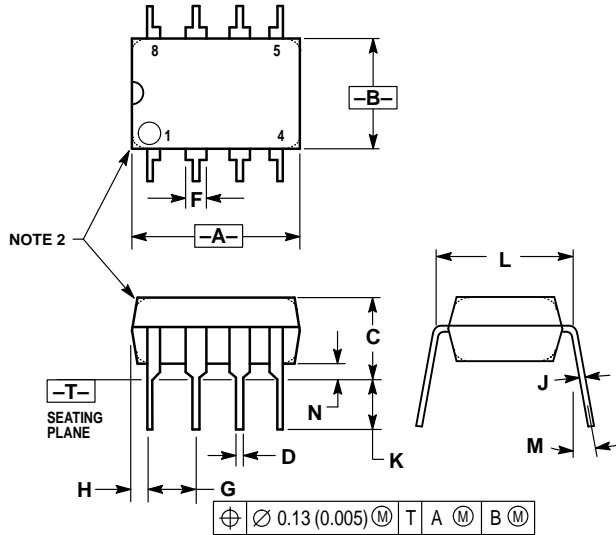
- Overshoot < 10%
- $t_s = 10 \mu\text{s}$
- When driving large C_L , the V_O slew rate is determined by C_L and $I_O(\text{max})$:

$$\frac{\Delta V_O}{\Delta t} = \frac{I_O}{C_L} \cong \frac{0.02}{0.5} \text{ V}/\mu\text{s} = 0.04 \text{ V}/\mu\text{s} \text{ (with } C_L \text{ shown)}$$

TL081C,AC TL082C,AC TL084C,AC

OUTLINE DIMENSIONS

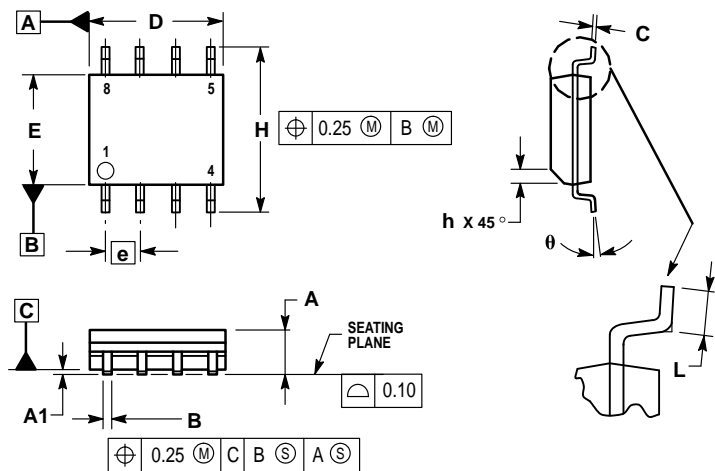
P SUFFIX
PLASTIC PACKAGE
CASE 626-05
ISSUE K



- NOTES:
1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
 2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
B	6.10	6.60	0.240	0.260
C	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	10°		10°	
N	0.76	1.01	0.030	0.040

D SUFFIX
PLASTIC PACKAGE
CASE 751-05
(SO-8)
ISSUE S



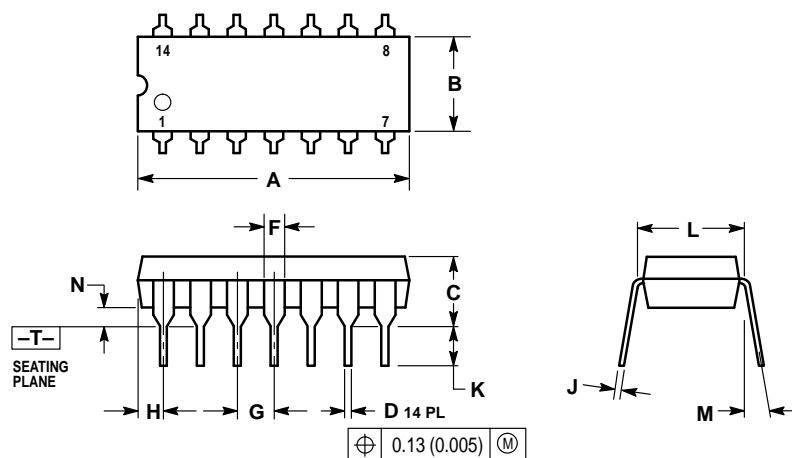
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. DIMENSIONS ARE IN MILLIMETERS.
 3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 5. DIMENSION B DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	1.35	1.75
A1	0.10	0.25
B	0.35	0.49
C	0.18	0.25
D	4.80	5.00
E	3.80	4.00
e	1.27 BSC	
H	5.80	6.20
h	0.25	0.50
L	0.40	1.25
θ	0°	7°

TL081C,AC TL082C,AC TL084C,AC

OUTLINE DIMENSIONS


N SUFFIX
PLASTIC PACKAGE
CASE 646-06
ISSUE M



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.715	0.770	18.16	18.80
B	0.240	0.260	6.10	6.60
C	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
H	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
M	— 10°		— 10°	
N	0.015	0.039	0.38	1.01

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TL081C/D